MARKING DIAGRAMS

Low-Voltage CMOS Quad 2-Input NOR Gate

With 5 V-Tolerant Inputs

MC74LCX02

The MC74LCX02 is a high performance, quad 2-input NOR gate operating from a 1.65 to 5.5 V supply. High impedance TTL compatible inputs significantly reduce current loading to input drivers while TTL compatible outputs offer improved switching noise performance. A V_I specification of 5.5 V allows MC74LCX02 inputs to be safely driven from 5 V devices.

Features

- Designed for 1.65 V to 5.5 V V_{CC} Operation
- 5 V Tolerant Inputs Interface Capability With 5 V TTL Logic
- LVTTL Compatible
- LVCMOS Compatible
- 24 mA Balanced Output Sink and Source Capability @ 3.0 V
- Near Zero Static Supply Current (10 µA) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds 100 mA
- ESD Performance: Human Body Model >2000 V
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

PIN NAMES

| Pins | Function |
|--------|-------------|
| An, Bn | Data Inputs |
| On | Outputs |

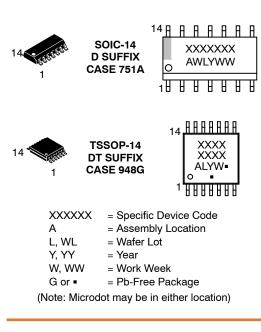
TRUTH TABLE

| Inputs | | Outputs | | |
|--------|----|---------|--|--|
| An | Bn | Ōn | | |
| L | L | Н | | |
| Н | н | L | | |
| Н | L | L | | |
| Н | Н | L | | |

H = High Voltage Level

L = Low Voltage Level

For I_{CC} reasons, DO NOT FLOAT Inputs



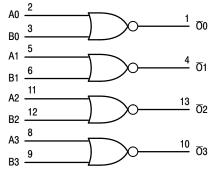
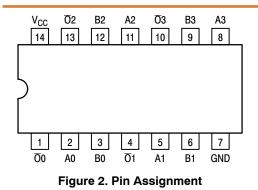


Figure 1. Logic Diagram



ORDERING INFORMATION

See detailed ordering and shipping information on page 6 of this data sheet.

MAXIMUM RATINGS

| Symbol | Param | Value | Unit | |
|--|---|--|---|------|
| V _{CC} | DC Supply Voltage | | –0.5 to +6.5 | V |
| VI | DC Input Voltage (Note 1) | | –0.5 to +6.5 | V |
| Vo | DC Output Voltage (Note 1) | Active-Mode (High or Low State) Tri-State Mode Power-Down Mode (V _{CC} = 0 V) | -0.5 to V _{CC} + 0.5 -0.5 to +6.5 -0.5 to +6.5 | V |
| I _{IK} | DC Input Diode Current | V _I < GND | -50 | mA |
| I _{OK} | DC Output Diode Current | V _O < GND | -50 | mA |
| Ι _Ο | DC Output Source/Sink Current | | ±50 | mA |
| I _{CC} or I _{GND} | DC Supply Current per Supply Pin or Grou | nd Pin | ±100 | mA |
| T _{STG} | Storage Temperature Range | | -65 to +150 | °C |
| ΤL | Lead Temperature, 1 mm from Case for 10 | secs | 260 | °C |
| ТJ | Junction Temperature Under Bias | | +150 | °C |
| θ_{JA} | Thermal Resistance (Note 1) | SOIC-14 QFN14 TSSOP-14 | 116 130 150 | °C/W |
| P _D | Power Dissipation in Still Air at 125°C | SOIC-14 QFN14 TSSOP-14 | 1077 962 833 | mW |
| MSL | Moisture Sensitivity | | Level 1 | - |
| F _R | Flammability Rating Oxygen Index: 28 to 3 | 4 | UL 94 V-0 @ 0.125 in | - |
| V_{ESD} | ESD Withstand Voltage (Note 3) | Human Body Model Charged Device Model | 2000 N/A | V |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. I_O absolute maximum rating must be observed.

 Measured with minimum pad spacing on an FR4 board, using 76 mm-by-114 mm, 2-ounce copper trace no air flow per JESD51-7.
 HBM tested to EIA / JESD22-A114-A. CDM tested to JESD22-C101-A. JEDEC recommends that ESD qualification to EIA/JESD22-A115A (Machine Model) be discontinued.

RECOMMENDED OPERATING CONDITIONS

| Symbol | | Min | Тур | Max | Unit | |
|---------------------------------|--------------------------|--|-----|-----|-----------------|------|
| V _{CC} | Supply Voltage | 1.65 | 3.3 | 5.5 | V | |
| | | Data Retention Only | 1.5 | 3.3 | 5.5 | |
| VI | Digital Input Voltage | | 0 | - | 5.5 | V |
| Vo | Output Voltage | Active Mode (High or Low State) | 0 | - | V _{CC} | V |
| | | Tri-State Mode | 0 | - | 5.5 | |
| | | Power Down Mode ($V_{CC} = 0 V$) | 0 | - | 5.5 | |
| T _A | Operating Free-Air Tempe | rature | -40 | - | +125 | °C |
| t _r , t _f | Input Rise or Fall Rate | V _{CC} = 1.65 V to 1.95 V | 0 | - | 20 | nS/V |
| | | V _{CC} = 2.3 V to 2.7 V | 0 | - | 20 | |
| | | V_{I} from 0.8 V to 2.0 V, V_{CC} = 3.0 V | 0 | - | 10 | |
| | | $V_{CC} = 4.5 \text{ V} \text{ to } 5.5 \text{ V}$ | 0 | - | 5 | |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.
Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

DC ELECTRICAL CHARACTERISTICS

| | Parameter | | | T _A = -40 °C to +85 °C | | $T_A = -40 \ ^\circ C$ to +125 $^\circ C$ | | | |
|------------------|---------------------------------------|---|---|--|---|---|---|--------|--|
| Symbol | | Conditions | V _{CC} (V) | Min | Max | Min | Max | Unit | |
| V _{IH} | HIGH Level Input Voltage | | 1.65–1.95 | 0.65 x V _{CC} | - | 0.65 x V _{CC} | _ | V | |
| | | | 2.3–2.7 | 1.7 | - | 1.7 | - | | |
| | | | 3.0-3.6 | 2.0 | - | 2.0 | - | | |
| | | | 4.5–5.5 | 0.70 x V _{CC} | - | 0.70 x V _{CC} | - | | |
| V _{IL} | LOW Level Input Voltage | | 1.65–1.95 | - | 0.35 x V _{CC} | - | 0.35 x V _{CC} | V | |
| | | | 2.3–2.7 | - | 0.7 | - | 0.7 | | |
| | | | 3.0-3.6 | - | 0.8 | - | 0.8 | | |
| | | | 4.5–5.5 | - | 0.30 x V _{CC} | - | 0.30 x V _{CC} | - | |
| V _{OH} | High-Level Output Voltage | $ \begin{array}{c} V_I = V_{IH} \mbox{ or } V_{IL} \\ I_{OH} = -100 \ \mu A \\ I_{OH} = -4 \ m A \\ I_{OH} = -8 \ m A \\ I_{OH} = -12 \ m A \\ I_{OH} = -12 \ m A \\ I_{OH} = -12 \ m A \\ I_{OH} = -24 \ m A \\ I_{OH} = -24 \ m A \\ I_{OH} = -32 \ m A \\ I_{OL} = -32 \ m A \\ I_{OL} = 100 \ \mu A \\ I_{OL} = 4 \ m A \\ I_{OL} = 12 \ m A \\ I_{OL} = 12 \ m A \\ I_{OL} = 16 \ m A \\ I_{OL} = 24 \ m A \end{array} $ | 1.65 to 5.5 1.65 2.3 2.7 3.0 3.0 4.5 1.65 to 5.5 1.65 2.3 2.7 3.0 3.0 | V _{CC} - 0.1 1.29 1.8 2.2 2.4 2.2 3.7 - - - - - - - - | - - - - - 0.1 0.24 0.3 0.4 0.4 0.55 | V _{CC} - 0.1 1.29 1.8 2.2 2.4 2.2 3.7 - - - - - - - | - - - - - - - 0.1 0.24 0.3 0.4 0.4 0.55 | V V | |
| l _l | Input Leakage Current | I _{OL} = 32 mA V _I = 0 to 5.5 V | 4.5 3.6 | _ | 0.6 ±5.0 | _ | 0.6 ±5.0 | μA | |
| I _{OFF} | Power Off Leakage Current | $V_{\rm I} = 5.5 \text{ V or}$ $V_{\rm O} = 5.5 \text{ V}$ | 0 | _ | ±3.0 10 | - | ±3.0 10 | μΑ | |
| Icc | Quiescent Supply Current | $V_{l} = 5.5 \text{ V or GND}$ | 3.6 | - | 10 | - | 10 | μA | |
| ΔI_{CC} | Increase in I _{CC} per Input | V _{IH} = V _{CC} – 0.6 V | 2.3 to 3.6 | - | 500 | - | 500 | μA | |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC ELECTRICAL CHARACTERISTICS

| | | | | $T_A = -40 \ ^\circ C$ to +85 $^\circ C$ | | $T_A = -40 \text{ °C to } +85 \text{ °C}$ $T_A = -40 \text{ °C to } +125 \text{ °C}$ | | c to +125 °C | |
|-------------------------------------|------------------------------------|------------------------|---------------------|--|------|--|------|--------------|--|
| Symbol | Parameter | Test Condition | V _{CC} (V) | Min | Max | Min | Мах | Unit | |
| t _{PLH} , t _{PHL} | Propagation Delay, Input to Output | See Figures 3 and 4 | 1.65 to 1.95 | - | 10.3 | - | 10.3 | ns | |
| | | | 2.3 to 2.7 | - | 6.6 | - | 6.6 | | |
| | | | 2.7 | - | 6.2 | - | 6.2 | | |
| | | | 3.0 to 3.6 | - | 5.5 | - | 5.5 | | |
| | | | 4.5 to 5.5 | - | 4.2 | - | 4.2 | | |

AC ELECTRICAL CHARACTERISTICS

| | | | | T _A = -40 °C | C to +85 °C | T _A = -40 °C | C to +125 °C | |
|--|-----------------------|----------------|---------------------|-------------------------|-------------|-------------------------|--------------|------|
| Symbol | Parameter | Test Condition | V _{CC} (V) | Min | Max | Min | Max | Unit |
| t _{OSHL} , t _{OSLH} | Output to Output Skew | | 1.65 to 1.95 | - | - | - | - | ns |
| | | | 2.3 to 2.7 | - | - | - | - | |
| | | | 2.7 | - | - | - | - | |
| | | | 3.0 to 3.6 | - | 1.0 | - | 1.0 | |
| | | | 4.5 to 5.5 | - | - | - | - | |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

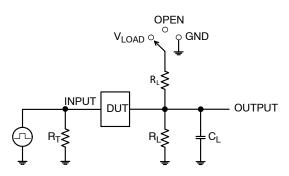
DYNAMIC SWITCHING CHARACTERISTICS

| | | | T _A = +25 °C | | | |
|------------------|----------------------------|---|-------------------------|------|-----|------|
| Symbol | Characteristic | Condition | Min | Тур | Max | Unit |
| V _{OLP} | Dynamic LOW Peak Voltage | V_{CC} = 3.3 V, C_L = 50 pF, V_{IH} = 3.3 V, V_{IL} = 0 V | | 0.8 | | V |
| | (Note 5) | V_{CC} = 2.5 V, C_L = 30 pF, V_{IH} = 2.5 V, V_{IL} = 0 V | | 0.6 | | V |
| V _{OLV} | Dynamic LOW Valley Voltage | V_{CC} = 3.3 V, C_L = 50 pF, V_{IH} = 3.3 V, V_{IL} = 0 V | | -0.8 | | V |
| | (Note 5) | V_{CC} = 2.5 V, C_L = 30 pF, V_{IH} = 2.5 V, V_{IL} = 0 V | | -0.6 | | V |

5. Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the LOW state.

CAPACITIVE CHARACTERISTICS

| Symbol | Parameter | Condition | Тур | Unit |
|------------------|-------------------------------|---|-----|------|
| C _{IN} | Input Capacitance | V_{CC} = 3.3 V, V_{I} = 0 V or V_{CC} | 7 | pF |
| C _{OUT} | Output Capacitance | V_{CC} = 3.3 V, V_{I} = 0 V or V_{CC} | 8 | pF |
| C _{PD} | Power Dissipation Capacitance | 10 MHz, V_{CC} = 3.3 V, V_{I} = 0 V or V_{CC} | 25 | pF |



٧...

| Test | Switch Position |
|-------------------------------------|-------------------|
| t _{PLH} / t _{PHL} | Open |
| t _{PLZ} / t _{PZL} | V _{LOAD} |
| t _{PHZ} / t _{PZH} | GND |

 C_L includes probe and jig capacitance R_T is Z_{OUT} of pulse generator (typically 50 $\Omega)$ f = 1 MHz

10%

tрн

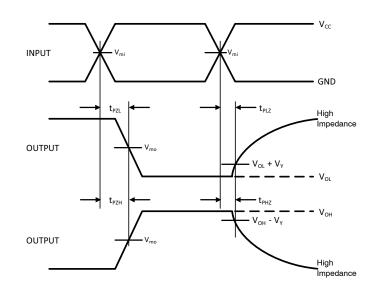
 t_{PLH}

t_r = 2.5 ns

INPUT

OUTPUT

OUTPUT



| Figure | 3. | Test | Circuit |
|--------|----|------|---------|
| iguio | υ. | 1001 | onoun |

t_f = 2.5 ns

10%

۷.

V_{ma}

t_{PLH}

 t_{PHL} Þ

Vcc

GND

V_{OH}

V_{OH}

 V_{OL}

-Vol

| V _{CC} , V | R_{L}, Ω | C _L , pF | V _{LOAD} | v _m , v | V _Y , V |
|---------------------|-----------------|---------------------|-------------------|--------------------|--------------------|
| 1.65 to 1.95 | 500 | 30 | $2 \times V_{CC}$ | V _{CC} /2 | 0.15 |
| 2.3 to 2.7 | 500 | 30 | $2 \times V_{CC}$ | V _{CC} /2 | 0.15 |
| 2.7 | 500 | 50 | 6 V | 1.5 | 0.3 |
| 3.0 to 3.6 | 500 | 50 | 6 V | 1.5 | 0.3 |
| 4.5 to 5.5 | 500 | 50 | $2 \times V_{CC}$ | V _{CC} /2 | 0.3 |

Figure 4. Switching Waveforms

ORDERING INFORMATION

| Device | Marking | Package | Shipping [†] |
|-------------------|----------|-----------|-----------------------|
| MC74LCX02DR2G | SOIC-14 | LCX02G | 2500 / Tape & Reel |
| MC74LCX02DTG | TSSOP-14 | LCX 02 | 96 Units / Rail |
| MC74LCX02DTR2G | TSSOP-14 | LCX 02 | 2500 / Tape & Reel |
| MC74LCX02DTR2G-Q* | TSSOP-14 | LCX 02 | 2500 / Tape & Reel |

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
 *-Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP

Capable.

onsemi



*For additional information on our Pb–Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

 DOCUMENT NUMBER:
 98ASB42565B
 Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.

 DESCRIPTION:
 SOIC-14 NB
 PAGE 1 OF 2

 onsemi and ONSEMi. are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi axis me any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

SOIC-14 CASE 751A-03 ISSUE L

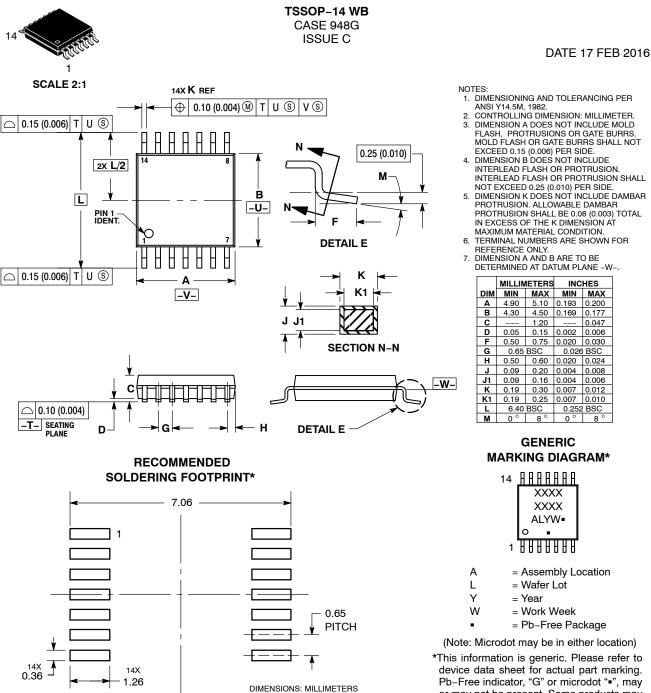
DATE 03 FEB 2016

| STYLE 1: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. NO CONNECTION 7. ANODE/CATHODE 9. ANODE/CATHODE 10. NO CONNECTION 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE | STYLE 2: CANCELLED | STYLE 3: PIN 1. NO CONNECTION 2. ANODE 3. ANODE 4. NO CONNECTION 5. ANODE 6. NO CONNECTION 7. ANODE 8. ANODE 9. ANODE 10. NO CONNECTION 11. ANODE 12. ANODE 13. NO CONNECTION 14. COMMON CATHODE | STYLE 4: PIN 1. NO CONNECTION 2. CATHODE 3. CATHODE 4. NO CONNECTION 5. CATHODE 6. NO CONNECTION 7. CATHODE 8. CATHODE 10. NO CONNECTION 11. CATHODE 12. CATHODE 13. NO CONNECTION 14. COMMON ANODE |
|---|---|---|--|
| STYLE 5: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. NO CONNECTION 7. COMMON ANODE 8. COMMON CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE | STYLE 6: PIN 1. CATHODE 2. CATHODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE 7. CATHODE 8. ANODE 9. ANODE 10. ANODE 11. ANODE 12. ANODE 13. ANODE 14. ANODE | STYLE 7: PIN 1. ANODE/CATHODE 2. COMMON ANODE 3. COMMON CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. ANODE/CATHODE 7. ANODE/CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. COMMON CATHODE 12. COMMON CATHODE 13. ANODE/CATHODE 14. ANODE/CATHODE | STYLE 8: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. ANODE/CATHODE 7. COMMON ANODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. NO CONNECTION 12. ANODE/CATHODE 13. ANODE/CATHODE 14. COMMON CATHODE |

| DESCRIPTION: SOIC-14 NB PAGE 2 OF | DOCUMENT NUMBER: | 98ASB42565B | Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. | |
|-----------------------------------|------------------|-------------|---|-------------|
| | DESCRIPTION: | SOIC-14 NB | | PAGE 2 OF 2 |

onsemi and ONSEMI: are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

semi



*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

- FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT
- INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

| DOCUMENT NUMBER: | 98ASH70246A Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. | | | | |
|---|---|--|-------------|--|--|
| DESCRIPTION: | TSSOP-14 WB | | PAGE 1 OF 1 | | |
| onsemi and ONSEM), are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves | | | | | |

the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent_Marking.pdf</u>. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or indental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification. Buyer shall indemnify and hold onsemi and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs,

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation onsemi Website: www.onsemi.com

ONLINE SUPPORT: <u>www.onsemi.com/support</u> For additional information, please contact your local Sales Representative at <u>www.onsemi.com/support/sales</u>

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

onsemi:

MC74LCX02DR2G MC74LCX02DTG MC74LCX02DTR2G